



MA4VAT2007-1061T

High IIP3 PIN Diode Variable Attenuator 1.70-2.00 GHz

Features

- · RoHs and ELV compliant
- Bandwidth: 1.70 GHz to 2.00 GHz
- 1.4 dB Insertion Loss, Typical
- 1.4:1 VSWR, Typical
- 23 dB Attenuation, Typical
- 50 dBm Input IP3, Typical (1 MHz Offset, @ + 0 dBm Pinc)
- 0 2.77 Volts Control Voltage @ 3 mA Typical

Extra Features

- Covers the following Bands:
 - DCS
 - PCS
 - UMTS/WCDMA/CDMA
 - TD-S CDMA
 - SCDMA
- Usable Bandwidth: 1.50 GHz to 2.50 GHz
- 2.0 dB Insertion Loss, Typical
- 2:1 VSWR, Typical
- 18.5 dB Attenuation, Typical

Description and Applications

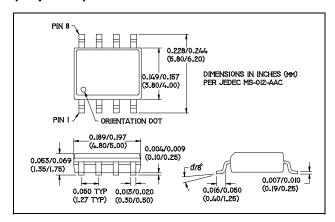
M/A-COM's MA4VAT2007-1061T is a HMIC PIN Diode Variable Attenuator which utilizes an integrated 90 degree 3dB hybrid with a pair of Silicon PIN Diodes to perform the required attenuation function as D.C. Voltage (Current) is applied.

This device operates from 0 to 2.77 Volts at 3.0mA typical control current for maximum attenuation. The user can add external biasing resistors to the bias ports for higher voltage requirements as required.

M/A-COM's MA4VAT2007-1061T PIN Diode Variable Attenuator is designed for AGC Circuit Applications requiring:

- Lower Insertion Loss
- Lower distortion through attenuation
- Large dynamic range for wide spread spectrum applications

PIN Configuration (Topview)



PIN Configuration (Topview)

PIN	Function	Comments		
1	DC1			
2	GND			
3	GND			
4	RFin/out	Symetrical as RF Input/Ouput		
5	RFout/in	Symetrical as RF Input/Ouput		
6	GND			
7	GND			
8	DC2			

Absolute Maximum Ratings^{1,2} @ T = +25 °C

Parameter	Maximum Ratings		
Operating Temperature	-40 °C to +85 °C		
Storage Temperature	-65 °C to +150 °C		
Junction Temperature	+175 °C		
RF C.W. Incident Power	+33 dBm C.W.		
Reversed Current @ -30 V	I -50nA I		
Control Current	50mA per Diode		

- 1. All the above are at Room Temperature except as noted
- 2. Exceeding the above Limits may cause permanent damage
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





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Electrical Specifications @ +25 °C

Parameter	Frequency Band	Unit	Min	Тур	Max	
No DC Bias Low Loss State (Pin = +10dBm, except for P1dB, & IP3)						
Insertion Loss	1.70 GHz – 2.00 GHz	dB	-	1.4	1.6	
Input Return Loss		dB	13	15	-	
Output Return Loss		dB	13	15	-	
P1dB		dBm	33	-	-	
IIP3		dBm	50	52	-	
Control Voltage		V	=	0V @ 0uA	-	
DC Bias RF Attenuation State (Pin = +10dBm, except for P1dB, & IP3)						
Maximum Attenuation	1.70 GHz – 2.00 GHz	dB	21	24	26	
Input Return Loss @ Max Attenuation		dB	19	21	-	
Output Return Loss @ Max Attenuation		dB	19	21	-	
Input IP3		dBm	40	42	-	
Control Voltage @ Max Attenuation		V	-	2.77V @ 3.00mA	-	

Typical RF Performance Over Industry Designated RF Frequency Bands

Band		Freq	I. Loss	Att.	R. Loss	IIP3	Phase -Relative-
		(MHz)	(dB)	(dB)	(dB)	(dBm)	(Degree)
DCS	RX	1710-1785	1.6	22	13	50	+15°
	TX	1805-1880	1.6	22	13	50	
PCS	RX	1850-1910	1.6	21	13	50	+10°
	TX	1930-1990	1.6	21	13	50	
UMTS	RX	1920-1980	1.6	20	13	50	-5°
WCDMA/CDMA	TX	2110-2170	1.8	20	13	50	
TD-S-CDMA	-	2010-2025	1.7	20	13	50	-2°
SCDMA	-	1800-2200	1.8	20	13	50	-10°

^{1.} All are typical values only.

information.

^{2.} Relative phase is the measured Insertion Phase Difference between Insertion Loss and the 20dB Attenuation State. (Please refer to the plots below)

M/A-COM Inc. and its affiliates reserve the right to make changes to the

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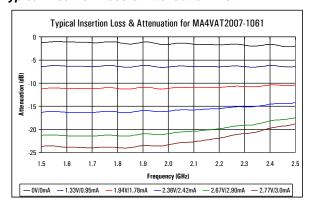


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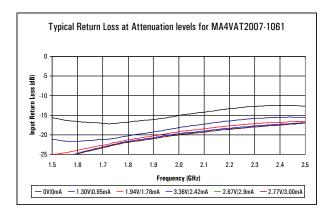
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Plots of Typical RF Characteristics @ + 25 °C

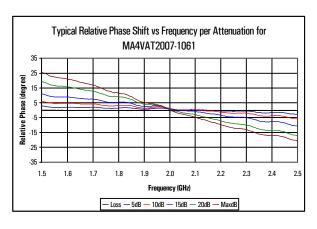
Typical Insertion Loss & Attenuation Plot



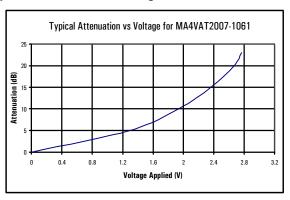
Typical Return Loss @ All Attenuation Levels Plot



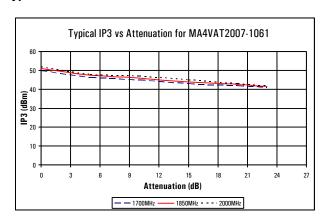
Typical Relative Phase Shift Per Attenuation (Voltage) Plot



Typical Attenuation Vs Voltage Plot



Typical IIP3 Vs Attenuation Plot



For Reference ONLY:

Low Loss = 0.00V, @0.00mA
5 dB Attenuation = 1.30V, @0.95mA
10 dB Attenuation = 1.94V, @1.78mA
15 dB Attenuation = 2.36V, @2.42mA
20 dB Attenuation = 2.67V, @2.90mA
Max Attenuation = 2.77V, @3.00mA

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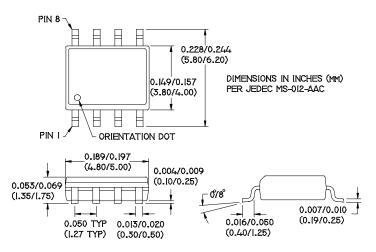


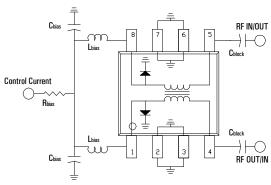


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Package Pin Designation, External Components, and Equivalent Circuit





External Bias Components

Rbias= 680 Ohms (2.77 V, 3.0 mA) Lbias= 150 nH Cbias =100 pF Cblock =100 pF

Ordering Information

Part Number	Package		
MA4VAT2007-1061T	Tape and Reel		

information.

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